B0530WS Taiwan Semiconductor

500mA, 30V Schottky Barrier Diode

FEATURES

- · Designed for mounting on small surface
- Low Capacitance
- Low forward voltage drop
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Adapters
- For switching power supply
- Low stored charge
- Inverter •

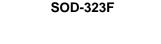
MECHANICAL DATA

- Case: SOD-323F
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- · Polarity: Indicated by cathode band
- Weight: 4.60mg (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I _F	500	mA	
V _{RRM}	30	V	
I _{FSM}	5	А	
V_F at I_F = 500mA	0.47	V	
T _{J MAX}	125 °C		
Package	SOD-323F		
Configuration	Single die		









ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER		SYMBOL	B0530WS	UNIT
Marking code on the device			B3	
Repetitive peak reverse voltage		V _{RRM}	30	V
Forward current		I _F	500	mA
Non-repetitive peak forward surge current	t = 8.3ms	I _{FSM}	5	А
Junction temperature range		TJ	-65 to +125	°C
Storage temperature range		T _{STG}	-65 to +125	°C

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-ambient thermal resistance	R _{eja}	426	°C/W





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ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage ⁽¹⁾	$I_{\rm F} = 100 {\rm mA}, {\rm T}_{\rm J} = 25^{\circ}{\rm C}$	V _F	-	0.36	V
Forward voltage $I_F =$	$I_F = 500 \text{mA}, T_J = 25^{\circ}\text{C}$		-	0.47	V
	$V_{R} = 15V, T_{J} = 25^{\circ}C$	-	80	μA	
Reverse current @ rated $V_R^{(2)}$	$V_{R} = 20V, T_{J} = 25^{\circ}C$	I _R	-	100	μA
	$V_{R} = 30V, T_{J} = 25^{\circ}C$		-	500	μA
Junction capacitance	1MHz, $V_R = 0V$	CJ	-	160	pF

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION			
ORDERING CODE	PACKAGE	PACKING	
B0530WS RRG	SOD-323F	3,000 / 7" Tape & Reel	
B0530WS R9G	SOD-323F	10,000 / 13" Tape & Reel	



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

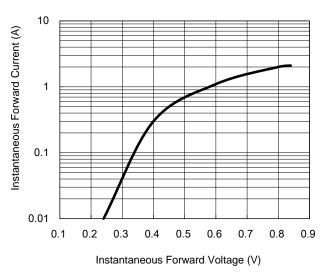


Fig.1 Typical Forward Characteristics

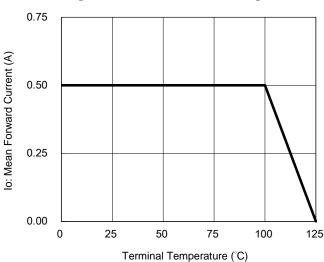
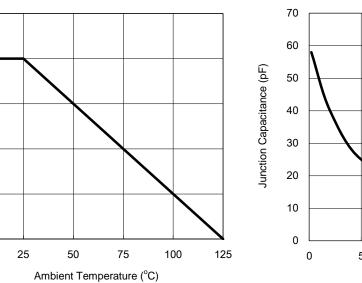


Fig.2 Forward Current Derating Curve



Power Dissipation (mW)

Fig.4 Typical Junction Capacitance



Reverse Voltage (V)



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

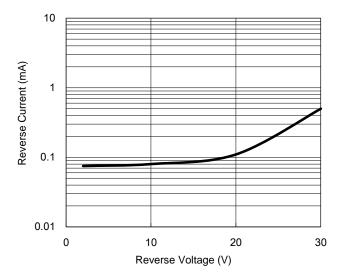
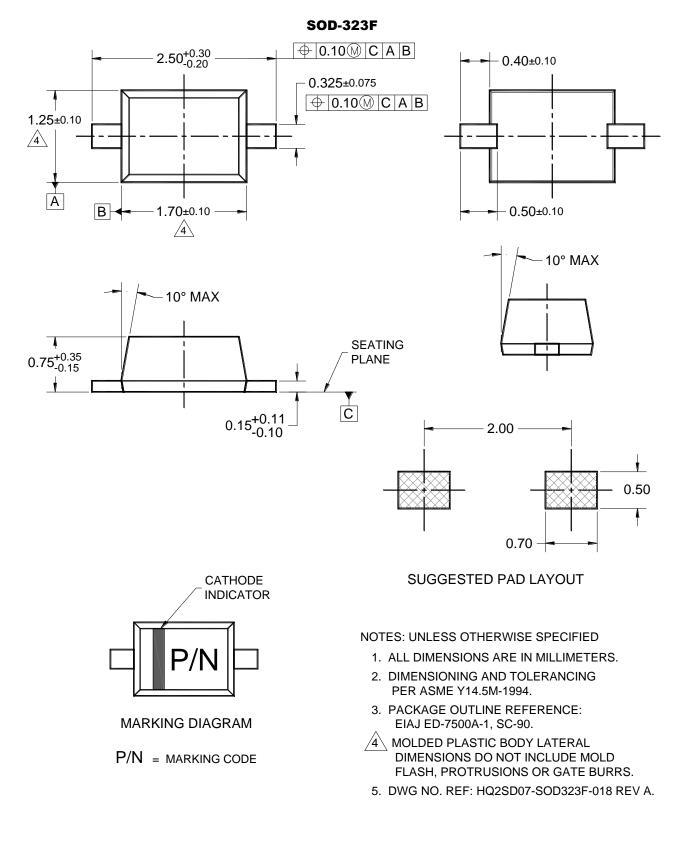


Fig.5 Typical Reverse Characteristics



PACKAGE OUTLINE DIMENSIONS





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